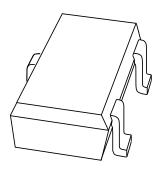
DISCRETE SEMICONDUCTORS

DATA SHEET



BAP63-05WSilicon PIN diode

Product specification Supersedes data of 2001 Apr 04 2001 May 18



Silicon PIN diode BAP63-05W

FEATURES

- High speed switching for RF signals
- · Low diode capacitance
- Low diode forward resistance
- Low series inductance
- For applications up to 3 GHz.

APPLICATIONS

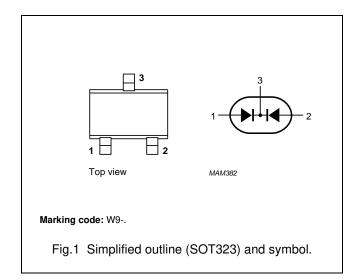
· RF attenuators and switches.

DESCRIPTION

Two planar PIN diodes in common cathode configuration in a SOT323 small SMD plastic package.

PINNING

PIN	DESCRIPTION
1	anode (a1)
2	anode (a2)
3	common cathode



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT
Per diode					
V _R	continuous reverse voltage		_	50	V
I _F	continuous forward current		-	100	mA
P _{tot}	total power dissipation	T _s ≤ 90 °C	_	240	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-65	+150	°C

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ELECTRICAL CHARACTERISTICS

 $T_j = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT			
Per diode								
V _F	forward voltage	I _F = 50 mA	0.95	1.1	V			
I _R	reverse current	V _R = 35 V	_	10	nA			
C _d	diode capacitance	V _R = 0; f = 1 MHz	0.4	_	pF			
		V _R = 1 V; f = 1 MHz	0.35	_	pF			
		V _R = 20 V; f = 1 MHz	0.3	0.35	pF			
r _D	diode forward resistance	I _F = 0.5 mA; f = 100 MHz; note 1	2.5	3.5	Ω			
		$I_F = 1 \text{ mA}$; f = 100 MHz; note 1	1.95	3	Ω			
		I _F = 10 mA; f = 100 MHz; note 1	1.17	1.8	Ω			
		$I_F = 100 \text{ mA}$; $f = 100 \text{ MHz}$; note 1	0.9	1.5	Ω			
$ s_{21} ^2$	isolation	$V_R = 0$; $f = 900 \text{ MHz}$	14.5	_	dB			
		V _R = 0; f = 1800 MHz	9.5	_	dB			
		$V_R = 0$; $f = 2450 \text{ MHz}$	7.0	_	dB			
$ s_{21} ^2$	insertion loss	$I_F = 0.5 \text{ mA}$; $f = 900 \text{ MHz}$	0.23	_	dB			
		$I_F = 0.5 \text{ mA}$; $f = 1800 \text{ MHz}$	0.27	_	dB			
		$I_F = 0.5 \text{ mA}$; $f = 2450 \text{ MHz}$	0.33	_	dB			
$ s_{21} ^2$	insertion loss	$I_F = 1 \text{ mA}; f = 900 \text{ MHz}$	0.19	_	dB			
		$I_F = 1 \text{ mA}$; $f = 1800 \text{ MHz}$	0.24	_	dB			
		$I_F = 1 \text{ mA}; f = 2450 \text{ MHz}$	0.30	_	dB			
$ s_{21} ^2$	insertion loss	I _F = 10 mA; f = 900 MHz	0.14	_	dB			
		$I_F = 10 \text{ mA}$; $f = 1800 \text{ MHz}$	0.19	_	dB			
		$I_F = 10 \text{ mA}$; $f = 2450 \text{ MHz}$	0.25	_	dB			
$ s_{21} ^2$	insertion loss	$I_F = 100 \text{ mA}$; $f = 900 \text{ MHz}$	0.11	_	dB			
		I _F = 100 mA; f = 1800 MHz	0.17	_	dB			
		I _F = 100 mA; f = 2450 MHz	0.23	_	dB			
τ∟	charge carrier life time	when switched from I _F = 10 mA to I _R = 6 mA; R _L = 100 Ω ; measured at I _R = 3 mA	310	-	ns			
L _S	series inductance	I _F = 100 mA; f = 100 MHz	1.5		nH			
	•	•						

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	250	K/W

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GRAPHICAL DATA

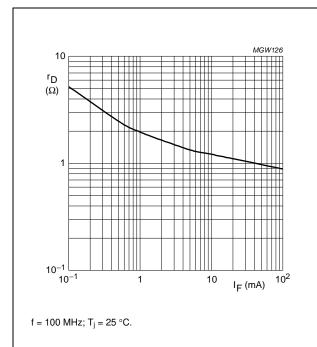


Fig.2 Forward resistance as a function of forward current; typical values.

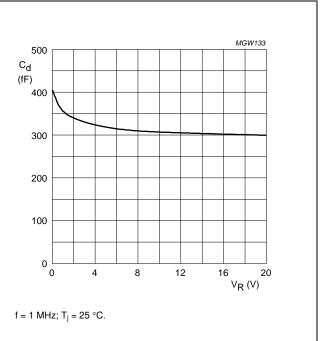
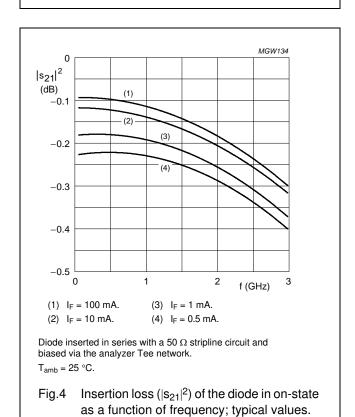
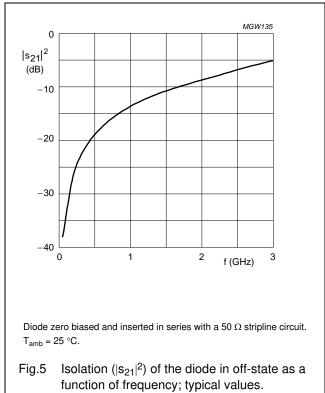


Fig.3 Diode capacitance as a function of reverse voltage; typical values.



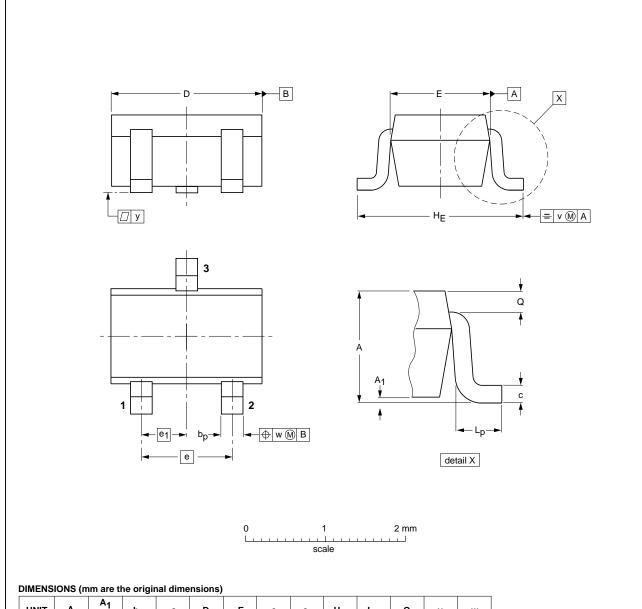


Silicon PIN diode BAP63-05W

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT323



UNIT	Α	A ₁ max	bp	С	D	E	е	e ₁	HE	Lp	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

	OUTLINE		REFER	EUROPEAN ISSUE DATE			
VERSION		IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	SOT323			SC-70			04-11-04 06-03-16

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DATA SHEET STATUS

DOCUMENT STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Contact information

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Printed in The Netherlands R77/03/pp8 Date of release: 2001 May 18